# NSN 5961-01-150-1789

Transistor - Page 1 of 2



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# **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

# Overall Height:

0.450 inches

# Overall Width:

1.050 inches

# **End Application:**

6130-01-135-5065

# Mounting Facility Quantity:

2

# Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

# Electrode Internally-electrically Connected To Case:

Collector

# **Mounting Method:**

Unthreaded hole

# **Features Provided:**

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

160.0 collector to base voltage/static/emitter open and 140.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

Between 4.00 amperes source cutoff current and 16.00 amperes source cutoff current

# Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# **Terminal Type And Quantity:**

1 case and 2 pin

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

# **NSN 5961-01-150-1789** Transistor - Page 2 of 2

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